

Surface Mount Switching Diode

BAS16W, BAS19W, BAS20W, BAS21W

Voltage: 75 - 200 Volts

Power: 200 mWatts

Features

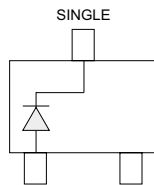
Fast SwitchingSpeed
Surface Mount Package Ideally Suited for
Automatic Insertion
Electrically Identical to Standard JEDEC
High Conductance

Mechanical data

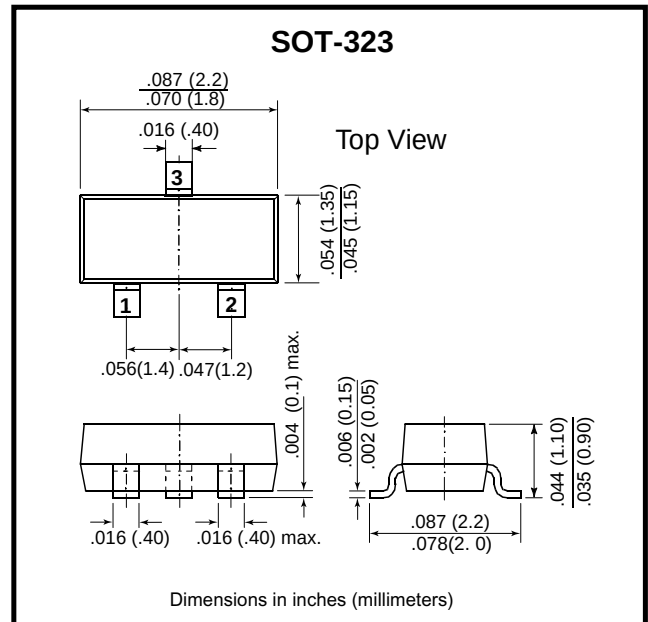
Case: SOT -23, Plastic

Terminals : Solderable per NIL-STD -202,
method 208

Approx. Weight: 0.008 gram



BAS16W, BAS19W, BAS20W, BAS21W



Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

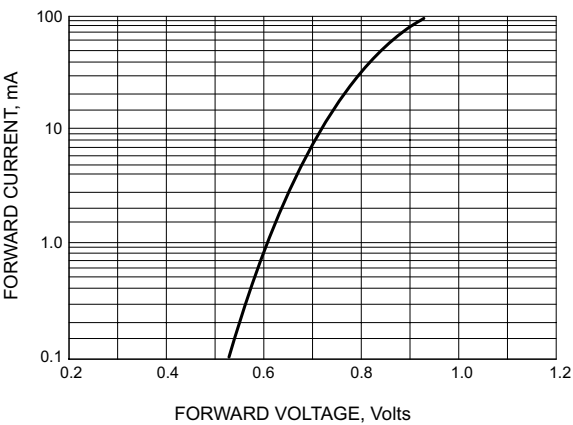
Parameter	Symbol	BAS16W	BAS19W	BAS20W	BAS21W	UNITS
Reverse Voltage	V_R	75	100	150	200	V
Peak Reverse Voltage	V_{RM}	100	120	200	250	V
Rectified Current (Average), Half Wave Rectification with Resistive Load and $f \geq 50$ Hz	I_O	250	200	200	200	mA
Peak Forward Surge Current, 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	2.0	2.5	2.5	2.5	A
Power Dissipation Derate Above 25°C	P_{TOT}	200	200	200	200	mW
Maximum Forward Voltage @ $I_F=10mA$ @ $I_F=100mA$	V_F	0.855	1.0	1.0	1.0	V
Maximum DC Reverse Current at Rated DC Blocking Voltage $T_J = 25^\circ C$	I_R	1.0	0.1	0.1	0.1	μA
Typical Junction Capacitance (Notes1)	C_J	2.0	1.5	1.5	1.5	pF
Maximum Reverse Recovery (Notes2)	T_{RR}	6.0	50.0	50.0	50.0	nS
Maximum Thermal Resistance	R_{JA}	357				$^\circ C/W$
Storage Temperature Range	T_J	-55 to +125				$^\circ C$

NOTE:

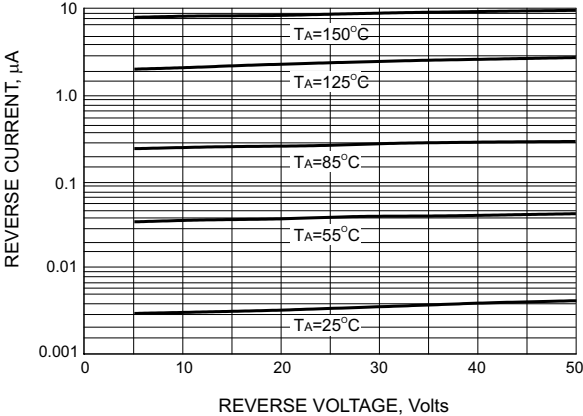
1. C_J at $V_R=0$, $f=1MHz$

2. From $I_F=10mA$ to $I_R=1mA$, $V_R=6Volts$, $R_L=100\Omega$

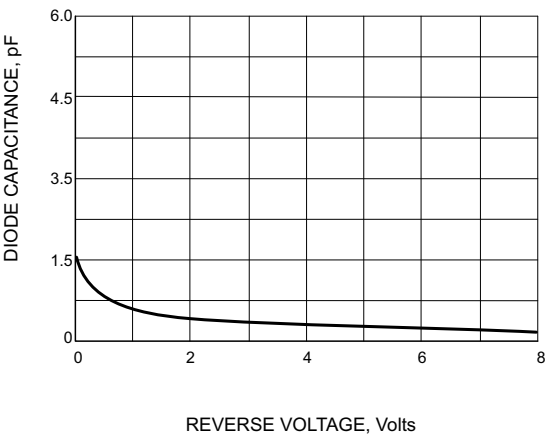
Rating and Characteristic Curves



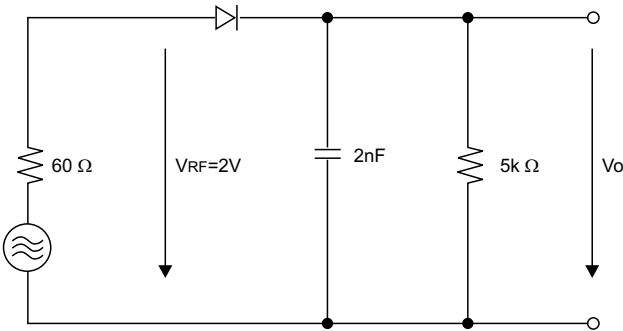
FORWARD VOLTAGE



LEAKAGE CURRENT



TYPICAL CAPATICANCE



RECTIFICATION EFFICIENCY MEASUREMENT CIRCUIT